

PMBT2222; PMBT2222A

NPN switching transistors

Rev. 6 — 12 November 2010

Product data sheet

1. Product profile

1.1 General description

NPN switching transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package	PNP complement	
	NXP	JEDEC	
PMBT2222	SOT23	TO-236AB	PMBT2907
PMBT2222A	•		PMBT2907A

1.2 Features and benefits

- High current (max. 600 mA)
- Low voltage (max. 40 V)

1.3 Applications

■ Switching and linear amplification

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base				
	PMBT2222		-	-	30	V
	PMBT2222A		-	-	40	V
I _C	collector current		-	-	600	mA
h _{FE}	DC current gain	V _{CE} = 10 V; I _C = 150 mA	<u>데</u> 100	-	300	
	PMBT2222	$V_{CE} = 10 \text{ V};$ $I_{C} = 500 \text{ mA}$	<u>[1]</u> 30	-	-	
	PMBT2222A	$V_{CE} = 10 \text{ V};$ $I_{C} = 500 \text{ mA}$	<u>[1]</u> 40	-	-	

^[1] Pulse test: $t_p \le 300~\mu s; \, \delta \le 0.02.$



2. Pinning information

Table 3. Pinning

Table 5.	i iiiiiiig		
Pin	Description	Simplified outline	Graphic symbol
1	base		_
2	emitter	3	3
3	collector	1 2	1 —
			svm021

3. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
PMBT2222	-	plastic surface-mounted package; 3 leads	SOT23
PMBT2222A	_		

4. Marking

Table 5. Marking codes

Type number	Marking code ^[1]
PMBT2222	*1B
PMBT2222A	*1P

^{[1] * =} placeholder for manufacturing site code

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter			
	PMBT2222		-	60	V
	PMBT2222A		-	75	V
V_{CEO}	collector-emitter voltage	open base			
	PMBT2222		-	30	V
	PMBT2222A		-	40	V
V_{EBO}	emitter-base voltage	open collector			
	PMBT2222		-	5	V
	PMBT2222A		-	6	V
Ic	collector current		-	600	mA
I _{CM}	peak collector current		-	800	mA
I _{BM}	peak base current		-	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] -	250	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		– 65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] -	-	500	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 8. Characteristics

 T_i = 25 °C unless otherwise specified.

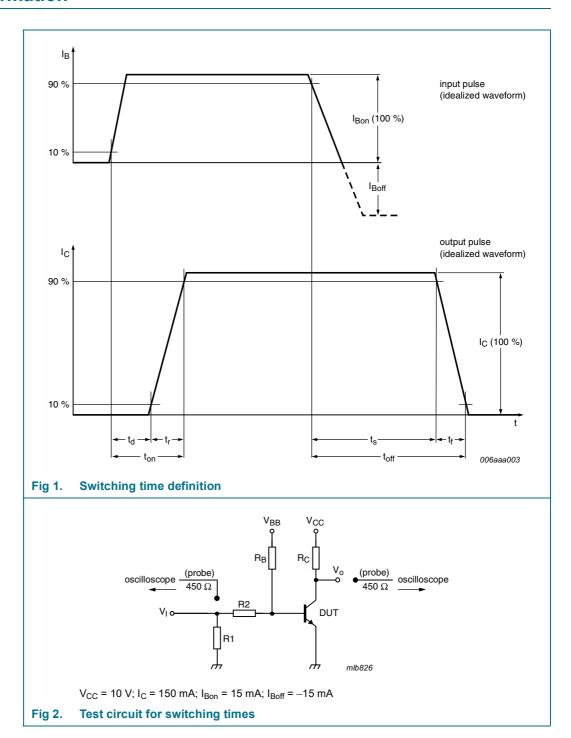
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current					
	PMBT2222	$V_{CB} = 50 \text{ V}; I_{E} = 0 \text{ A}$	-	-	10	nA
		$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A};$ $T_j = 125 \text{ °C}$	-	-	10	μΑ
	collector-base cut-off current					
	PMBT2222A	V _{CB} = 60 V; I _E = 0 A	-	-	10	nA
		$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A};$ $T_j = 125 \text{ °C}$	-	-	10	μА
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	10	nA
h _{FE}	DC current gain	$V_{CE} = 10 \text{ V};$ $I_{C} = 0.1 \text{ mA}$	35			
		V _{CE} = 10 V; I _C = 1 mA	50	-	-	
		V _{CE} = 10 V; I _C = 10 mA	75	-	-	
		$V_{CE} = 10 \text{ V};$ $I_{C} = 10 \text{ mA};$ $T_{amb} = -55 \text{ °C}$	35	-	-	
		V _{CE} = 10 V; I _C = 150 mA	[1] 100	-	300	
		V _{CE} = 1 V; I _C = 150 mA	<u>[1]</u> 50	-	-	
	DC current gain	$V_{CE} = 10 \text{ V};$ $I_{C} = 500 \text{ mA}$	<u>[1]</u>			
	PMBT2222		30	-	-	
	PMBT2222A		40	-	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 150 \text{ mA};$ $I_B = 15 \text{ mA}$	<u>[1]</u>			
	PMBT2222		-	-	400	mV
	PMBT2222A		-	-	300	mV
	collector-emitter saturation voltage	$I_C = 500 \text{ mA};$ $I_B = 50 \text{ mA}$	<u>[1]</u>			
	PMBT2222		-	-	1.6	V
	PMBT2222A		-	-	1	V

Table 8. Characteristics ...continued $T_i = 25 \, \circ \mathbb{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{BEsat}	base-emitter saturation voltage	I _C = 150 mA; I _B = 15 mA	<u>[1]</u>			
	PMBT2222		-	-	1.3	V
	PMBT2222A		0.6	-	1.2	V
	base-emitter saturation voltage	I _C = 500 mA; I _B = 50 mA	[1]			
	PMBT2222		-	-	2.6	V
	PMBT2222A		-	-	2	V
C _c	collector capacitance	$V_{CB} = 10 \text{ V};$ $I_E = i_e = 0 \text{ A};$ $f = 1 \text{ MHz}$	-	-	8	pF
C _e	emitter capacitance	$V_{EB} = 500 \text{ mV};$ $I_{C} = i_{c} = 0 \text{ A};$ f = 1 MHz				
	PMBT2222		-	-	30	pF
	PMBT2222A		-	-	25	pF
f _T	transition frequency	V _{CE} = 20 V; I _C = 20 mA; f = 100 MHz				
	PMBT2222		250	-	-	MHz
	PMBT2222A		300	-	-	MHz
NF	noise figure	V_{CE} = 5 V; I_{C} = 100 μ A; R_{S} = 1 k Ω ; f = 1 kHz	-	-	4	dB
t _d	delay time	V _{CC} = 10 V;	-	-	15	ns
t _r	rise time	¯ I _C = 150 mA; – I _{Bon} = 15 mA;	_	-	20	ns
t _{on}	turn-on time	$I_{Boff} = -15 \text{ mA}$	-	-	35	ns
t _s	storage time		-	-	200	ns
t _f	fall time	_	-	-	60	ns
t _{off}	turn-off time	_	-	-	250	ns

^[1] Pulse test: $t_p \le 300~\mu s$; $\delta \le 0.02$.

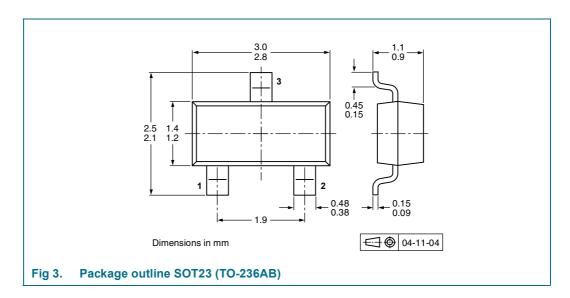
8. Test information



8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

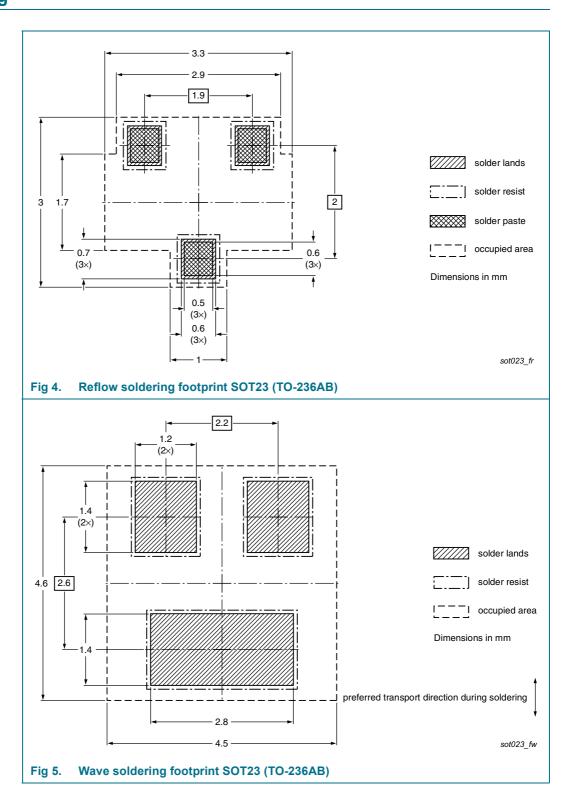
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Type number Package Description		Packing quantity		
			3000	10000	
PMBT2222	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235	
PMBT2222A	_				

^[1] For further information and the availability of packing methods, see <u>Section 14</u>.

11. Soldering



12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
PMBT2222_PMBT2222A v.6	20101112	Product data sheet	-	PMBT2222_2222A_5	
Modifications:	Section 4 "M	larking": updated			
	 Figure 1 "Sw 	vitching time definition": added	d		
	 Section 8 "Te 	Section 8 "Test information": updated			
	 Section 10 "I 	Packing information": added			
	 Section 11 "S 	Soldering": added			
	Section 13 "I	Legal information": updated			
PMBT2222_222A_5	20040122	Product specification	-	PMBT2222_2222A_4	
PMBT2222_222A_4	19990427	Product specification	-	PMBT2222_3	
PMBT2222_3	19970909	Product specification	-	-	

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
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NPN switching transistors

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